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Id: 202018241

Sheet 8:

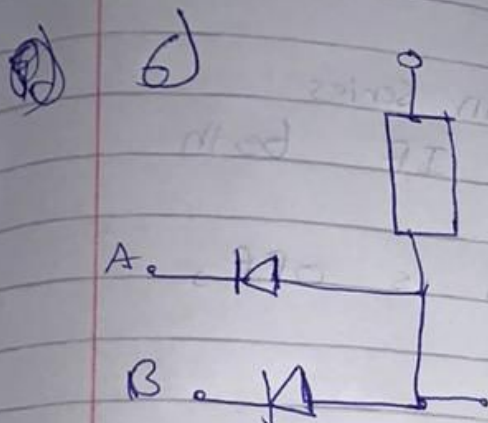
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Transistor AND gate

- 9) The two transistors are in series
- The output is High only IF both A and B are High
 - If one transistor, or both is OFF, output = 0 (low)

10) Transistor OR gate

- The output V_{out} (Q) is High if one or both transistors are ON, i.e. When A or B or Both are High. The output is Zero only if the transistors are OFF ($A=B=0$), in this case no current flows in emitter resistance and $V_{out} = 0$ (low)



$$V_{out} = A \cdot B$$

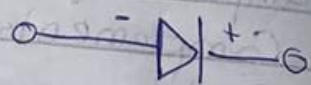
If and diode is connected to low Voltage (0) is forward biases and $V_{out} = 0$. The output is High only if the inputs to the two diodes are High and ~~both~~ both diodes are reverse biased. In this case no current flows in R and output = 5V (High).

7) When $V_{in} = 0$ (Low) Transistor Cut-off and $V_{out} = V_{cc}$ (High) (switch off)
 When $V_{in} > 0.7V$ (High) transistor in saturation, and $V_{out} = 0$ (Low) (switch is on)

8) If input is low, transistors is off then output is high and vice versa. Output is the complement (inverse) of the input.

Sheet B

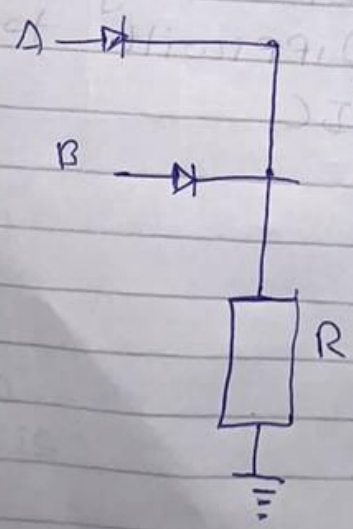
- 1) digital, finite, binary
- 2) False
- 3) Forward, Reverse
- 4)



When diode is forward biased (ON), when diode switch is open (OFF).

Switch is reverse biased.

5) OR GATE $V_{out} = A + B$
 IF A is High or Both A and B are High the output is High, since ~~both~~ diodes are forward biased and act as closed switches.



$$V_{out} = A + B$$

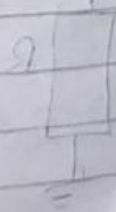
- 13) Small
- 14) Transistor
- 15) OFF, on
- 16) OFF
- 17) amplifier, amplifying
- 18) Complementary metal oxide Semiconductor
- 19) Field
- 20) MOSFET
- 21) Advantage
- 22)

FET

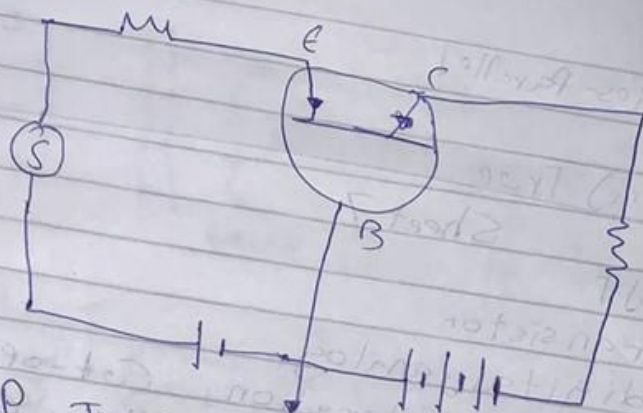
- Uni polar device
- Voltage Controlled Device
- High input impedance
- Better thermal stability
- High switching speeds
- Less Noisy
- Easy to fabricate

BJT

- Bipolar device
- Current controlled device
- low input impedance
- low thermal stability
- lower switching speed
- More noisy
- Difficult to fabricate on IC

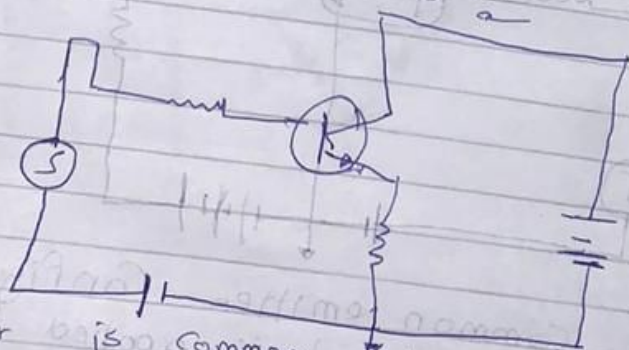


11)



- In PNP Transistor, Base - Emitter is forward biased, and Base - collector is reverse biased
- The Base is common between input and output
- No Current gain (I_c is less than I_e) but there is a Voltage gain

12)



- Collector is common between input and output
- $V_{out} = V_{in}$ So called emitter follower
- There is ~~no~~ Current gain but no Voltage gain
- Input impedance is high and output impedance is low

- 13) Sm
- 14) Tran
- 15) OF
- 16) OF
- 17) amp
- 18) Co
- 19) Fei
- 20) Mo
- 21) Ade
- 22)

- F
- Uni p
 - Voltage
 - Device
 - High
 - impedan
 - Better
 - stabilit
 - High
 - speeds
 - Less
 - Easy

27) Series-Parallel

28) a) True

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1) BJT Sheet 7

2) Transistor

3) digital, analog

4) Active

5) Saturation, Cut-off

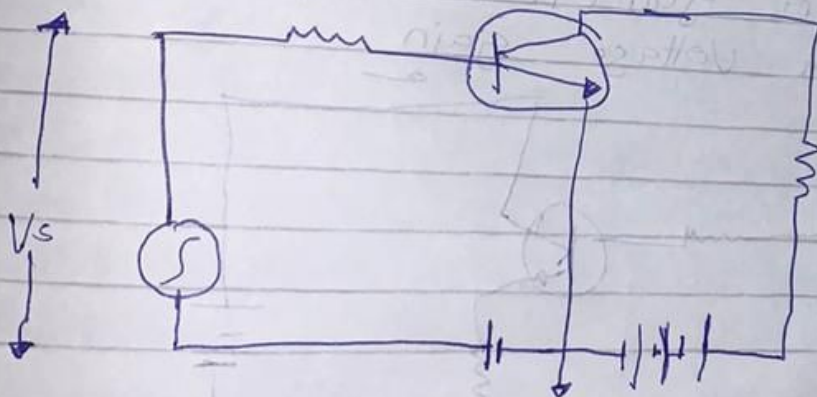
6) Base, Collector, Emitter, Base, Collector

7) Voltage

8) Voltage

9) Voltage

10)



In the common emitter configuration the input signal is applied between the base and emitter while the output is taken between collector and the emitter.